



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Bojarczuk, et al.

Serial No.: 09/755,164

Group Art Unit: 2826

Filed: January 8, 2001

Examiner: Quinto, Kevin V.

For: ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT
TRANSISTORS AND METHOD FOR FORMING SAME

Honorable Commissioner of Patents
Washington, D.C. 20231

AMENDMENT UNDER 37 C.F.R. §1.111

Sir:

In response to the Office Action dated January 30, 2003, please amend the above-identified application as follows:

INTRODUCTORY COMMENTS

Claims 1-7 and 14-18 are all the claims presently pending in the application. Claims 1-7, 14-15 and 17 have been amended to more clearly define the invention and claims 8-13 and 19-27 have been canceled. Claims 1, 14-15 and 17 are independent.

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Quinto, B
Y Robinson
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